

Low capacitance unidirectional ESD protection diode

Rev. 1 — 19 April 2011

Product data sheet

1. Product profile

1.1 General description

Low capacitance unidirectional ElectroStatic Discharge (ESD) protection diode designed to protect one signal line from the damage caused by ESD and other transients. The device is housed in a SOD882D leadless ultra small Surface-Mounted Device (SMD) plastic package with visible and solderable side pads.

1.2 Features and benefits

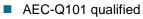
- ESD protection of one line
- Ultra small SMD plastic package
- Solderable side pads
- Package height typ. 0.37 mm
- Low diode capacitance C_d = 25 pF

1.3 Applications

- Computers and peripherals
- Audio and video equipment
- Communication systems
- Portable electronics

1.4 Quick reference data

Table 1.	Quick reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{RWM}	reverse standoff voltage		-	-	5	V
C _d	diode capacitance	f = 1 MHz; V _R = 0 V	-	25	30	pF



- ESD protection up to 26 kV
- IEC 61000-4-2; level 4 (ESD)
- IEC 61000-4-5 (surge); I_{PP} = 3.5 A
- Low clamping voltage: V_{CL} = 12 V



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2. Pinning information

Pin	Description	Simplified outline	Graphic symbol
1	cathode	<u>[1]</u>	
2	anode		1 2 006aaa152
		Transparent top view	

3. Ordering information

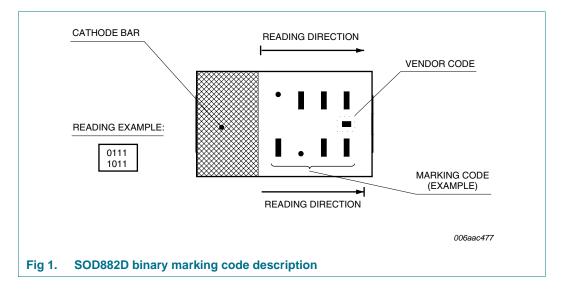
Table 3. Orderin	g informati	on	
Type number	Package		
	Name	Description	Version
PESD5V0L1ULD	-	leadless ultra small plastic package; 2 terminals; body 1 \times 0.6 \times 0.4 mm	SOD882D

4. Marking

Table 4. Marking codes	
Type number	Marking code ^[1]
PESD5V0L1ULD	1110 0000

[1] For SOD882D binary marking code description, see Figure 1.

4.1 Binary marking code description



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5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
P _{PP}	peak pulse power	$t_p = 8/20 \ \mu s$	[1][2] _	42	W
I _{PP}	peak pulse current	$t_p = 8/20 \ \mu s$	[1][2] _	3.5	А
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-55	+150	°C
T _{stg}	storage temperature		-65	+150	°C

[1] Non-repetitive current pulse 8/20 µs exponential decay waveform according to IEC 61000-4-5.

[2] Measured from pin 1 to 2.

Table 6.ESD maximum ratings

 $T_{amb} = 25 \ ^{\circ}C$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Max	Unit
- 100	electrostatic discharge voltage	IEC 61000-4-2 (contact discharge)	<u>[1][2]</u> _	26	kV
		machine model	-	400	V
		MIL-STD-883 (human body model)	[2] _	10	kV

[1] Device stressed with ten non-repetitive ESD pulses.

[2] Measured from pin 1 to 2.

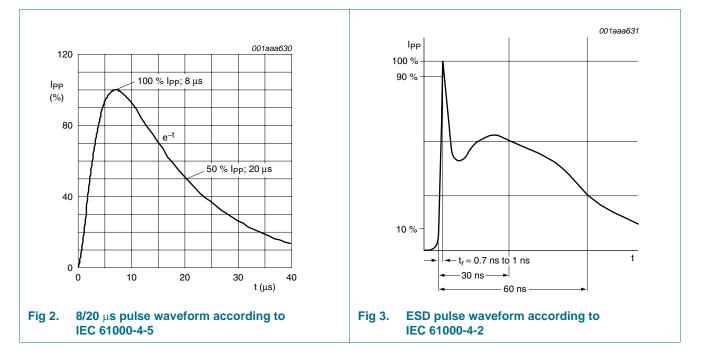
Table 7. ESD standards compliance

Standard	Conditions
IEC 61000-4-2; level 4 (ESD)	> 15 kV (air); > 8 kV (contact)
MIL-STD-883; class 3 (human body model)	> 4 kV

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6. Characteristics

Table 8.Characteristics

 $T_{amb} = 25$ °C unless otherwise specified.

Symbol	Parameter	Conditions	M	lin	Тур	Max	Unit
V _{RWM}	reverse standoff voltage		-		-	5	V
I _{RM}	reverse leakage current	$V_{RWM} = 5 V$	-		10	100	nA
V_{BR}	breakdown voltage	I _R = 5 mA	6	.4	6.8	7.2	V
C _d	diode capacitance	$f = 1 MHz; V_R = 0 V$	-		25	30	pF
V _{CL}	clamping voltage		<u>[1][2]</u>				
		I _{PP} = 1 A	-		-	9	V
		I _{PP} = 3.5 A	-		-	12	V
r _{dyn}	dynamic resistance	I _R = 10 A	[3] _		0.7	-	Ω

[1] Non-repetitive current pulse 8/20 µs exponential decay waveform according to IEC 61000-4-5.

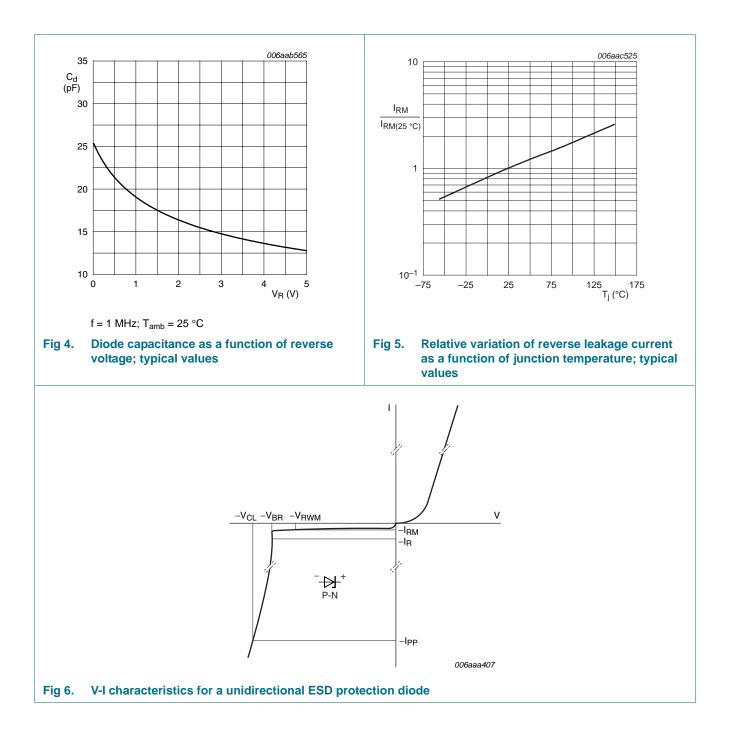
[2] Measured from pin 1 to 2.

[3] Non-repetitive current pulse, Transmission Line Pulse (TLP) $t_p = 100$ ns; square pulse; ANS/IESD STM5-1-2008.

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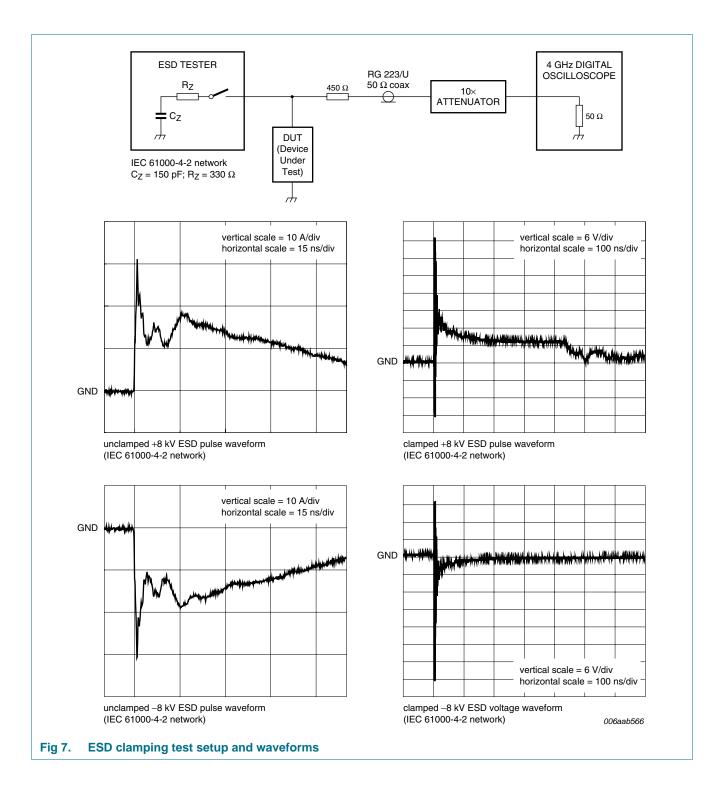
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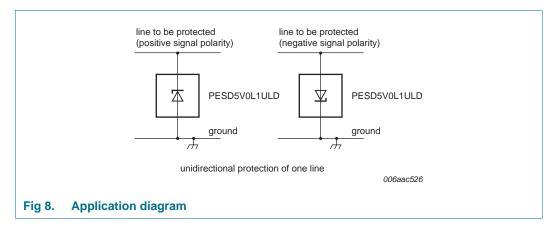


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7. Application information

The PESD5V0L1ULD is designed for the protection of one unidirectional data or signal line from the damage caused by ESD and surge pulses. The device may be used on lines where the signal polarities are either positive or negative with respect to ground.



Circuit board layout and protection device placement

Circuit board layout is critical for the suppression of ESD, Electrical Fast Transient (EFT) and surge transients. The following guidelines are recommended:

- 1. Place the PESD5V0L1ULD as close to the input terminal or connector as possible.
- The path length between the PESD5V0L1ULD and the protected line should be minimized.
- 3. Keep parallel signal paths to a minimum.
- 4. Avoid running protected conductors in parallel with unprotected conductors.
- 5. Minimize all Printed-Circuit Board (PCB) conductive loops including power and ground loops.
- 6. Minimize the length of the transient return path to ground.
- 7. Avoid using shared transient return paths to a common ground point.
- 8. Ground planes should be used whenever possible. For multilayer PCBs, use ground vias.

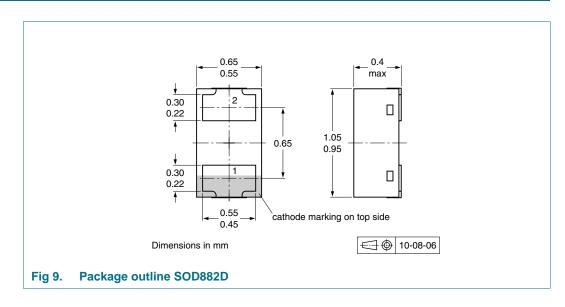
8. Test information

8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

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9. Package outline



10. Packing information

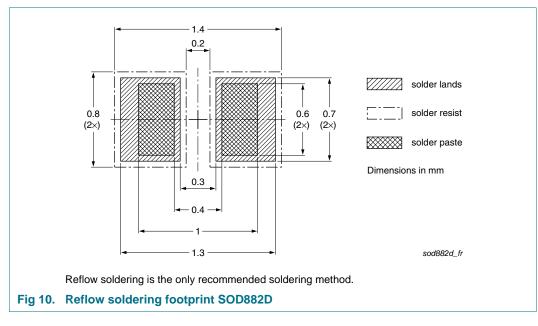
Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing quantity
			10000
PESD5V0L1ULD	SOD882D	2 mm pitch, 8 mm tape and reel	-315

[1] For further information and the availability of packing methods, see <u>Section 14</u>.

11. Soldering



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12. Revision history

Table 10. Revision history					
Document ID	Release date	Data sheet status	Change notice	Supersedes	
PESD5V0L1ULD v.1	20110419	Product data sheet	-	-	

13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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